

PNP SILICON EPITAXIAL PLANAR TRANSISTORS

BC556 ~ BC560



TO-92

TO-92 Leaded
Plastic Package
RoHS compliant

APPLICATION: For switching and AF amplifier application

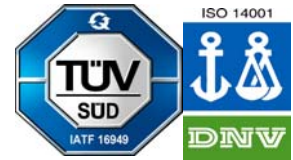
ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C Unless otherwise specified)

PARAMETER	SYMBOL	VALUE					UNIT
		BC556	BC557	BC560	BC558	BC559	
Collector Base Voltage	V_{CBO}	80	50	30			V
Collector Emitter Voltage	V_{CEO}	65	45	30			V
Emitter Base Voltage	V_{EBO}		5				V
Collector Current (DC)	I_C		100				mA
Collector Current - Peak	I_{CM}		200				mA
Power Dissipation	P_{tot}		500				mW
Storage Temperature	T_{stg}		-65 to +150				°C
Junction Temperature	T_j		150				°C



Continental Device India Pvt. Limited

An IATF 16949, ISO9001 and ISO 14001 Certified Company



ELECTRICAL CHARACTERISTICS at (Ta = 25 °C Unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITION	MIN	MAX	UNIT
DC Current Gain	h_{FE}	$I_C=2mA, V_{CE}=5V$	75	800	
		A	110	220	
		B	200	450	
		C	420	800	
Collector Emitter Saturation Voltage	$V_{CE(Sat)}$	$I_C=10mA, I_B=0.5mA$	--	0.30	V
		$I_C=100mA, I_B=5mA$	--	0.65	V
Base Emitter on Voltage	$V_{BE(on)}$	$I_C=2mA, V_{CE}=5V$	--	0.75	V
		$I_C=10mA, V_{CE}=5V$	--	0.82	V
Collector Base Cut off Current	I_{CBO}	$V_{CB}=30V, I_E=0$	--	15	nA
Emitter Base Cut off Current	I_{EBO}	$V_{EB}=5V$	--	100	nA
Collector Base Breakdown Voltage BC556 BC557 , BC560 BC558 , BC559	$V_{(BR)CBO}$	$I_C=100\mu A$	80	--	V
			50	--	
			30	--	
Collector Emitter Breakdown Voltage BC556 BC557 , BC560 BC558 , BC559	$V_{(BR)CEO}$	$I_C=2mA$	65	--	V
			45	--	
			30	--	
Emitter Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=100\mu A$	5	--	V
Transition Frequency	f_T		100	--	MHz
Collector Base Capacitance	C_{cb}	$V_{CB}=10V, f=1MHz$	--	6.0	pF

TYPICAL CHARACTERISTICS CURVES

Fig 1: Normalized DC Current Gain

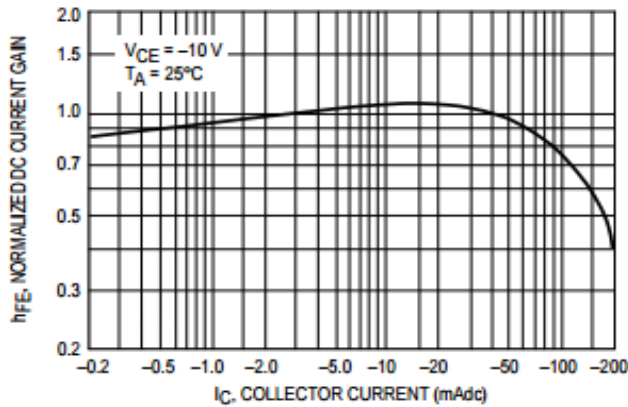


Fig 2: "Saturation" and "On" Voltages

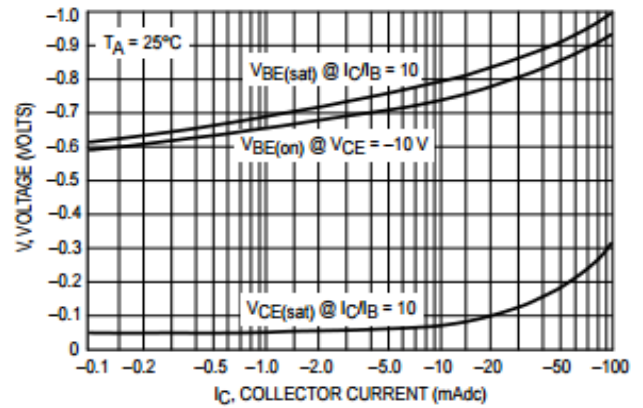


Fig 3: Collector Saturation Region

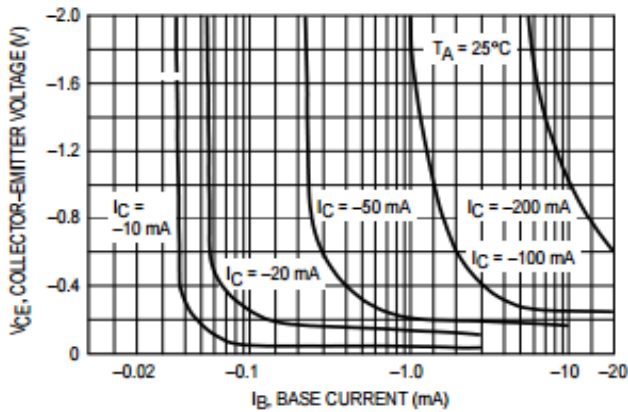


Fig 4: Base-Emitter Temperature Coefficient

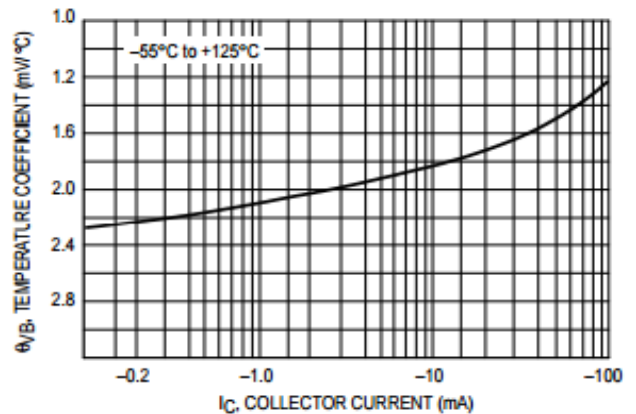


Fig 5: Capacitance

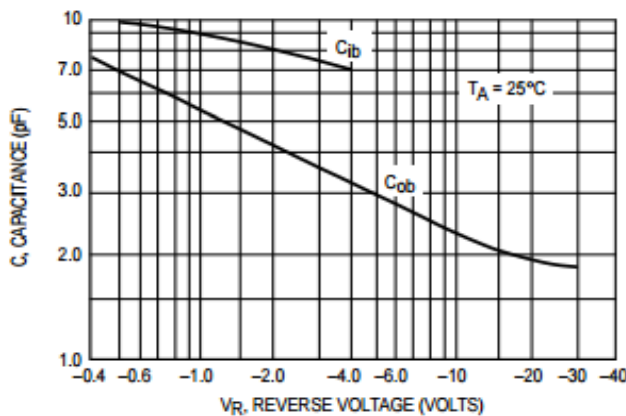
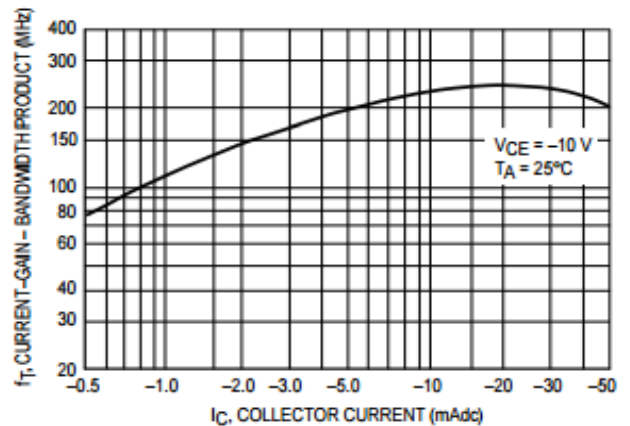


Fig 6: Current-Gain – Bandwidth Product



TYPICAL CHARACTERISTICS CURVES

Fig 7: DC Current Gain

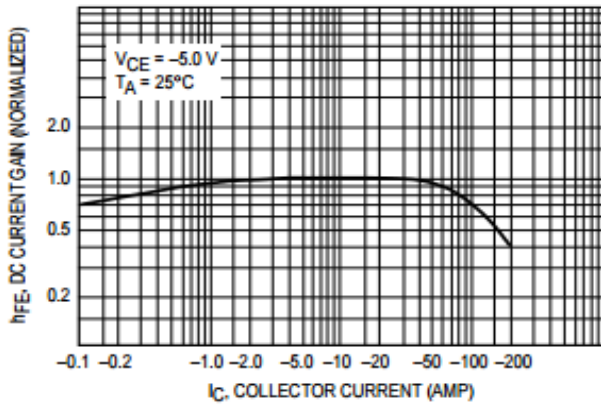


Fig 8: "On" Voltage

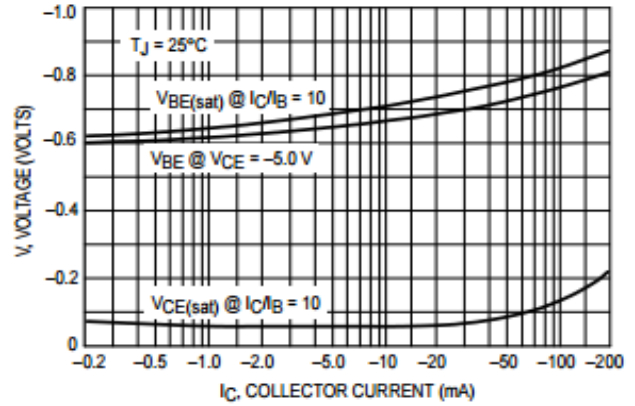


Fig 9: Collector Saturation Region

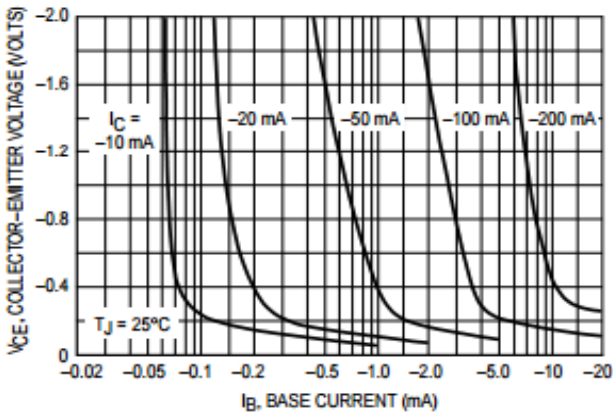


Fig 10: Base-Emitter Temperature Coefficient

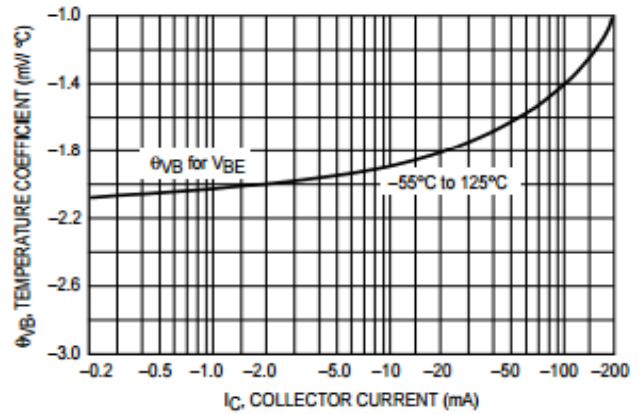


Fig 11: Capacitance

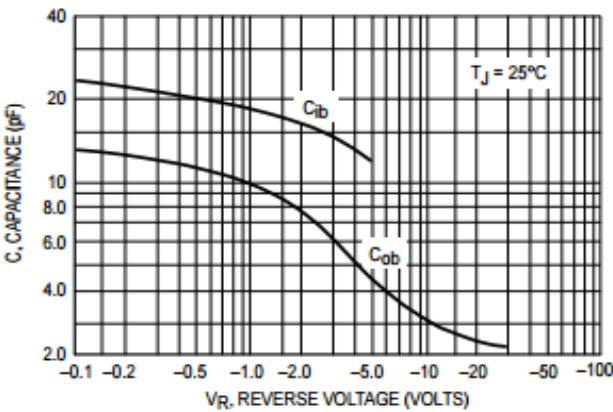
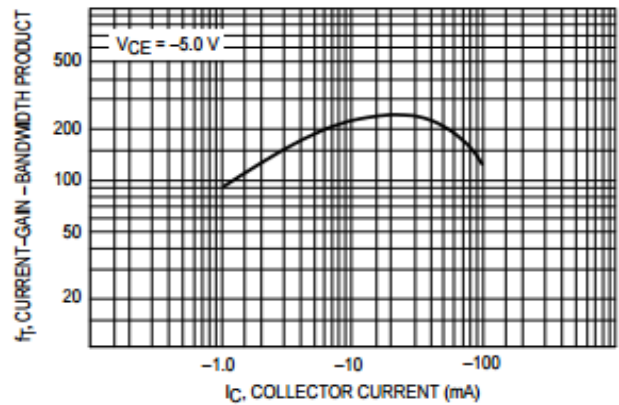


Fig 12: Current-Gain – Bandwidth Product



TYPICAL CHARACTERISTICS CURVES

Fig 13: Thermal Response

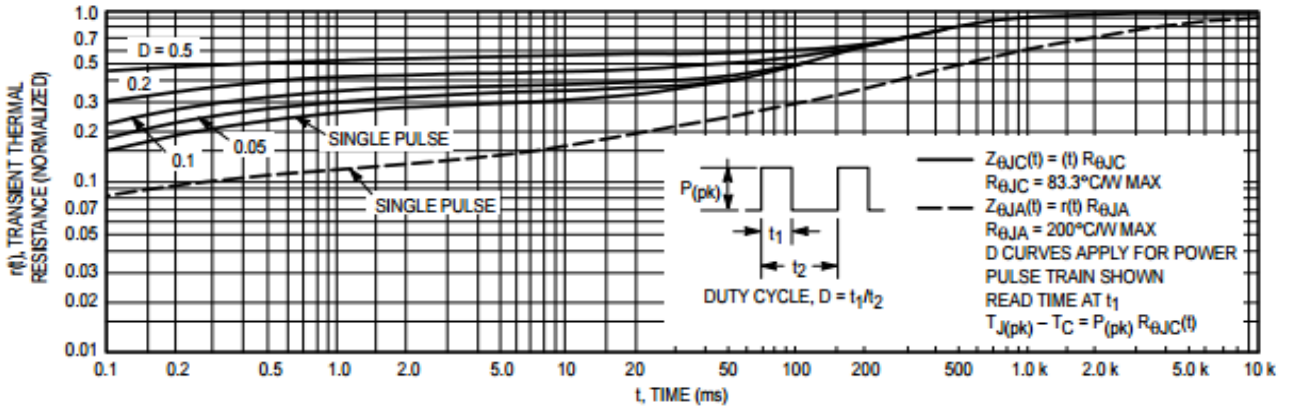
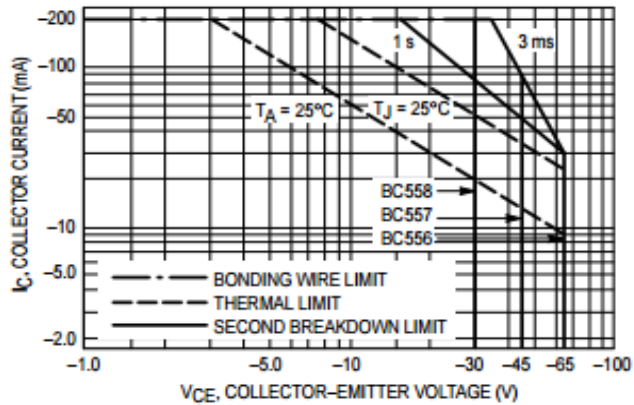
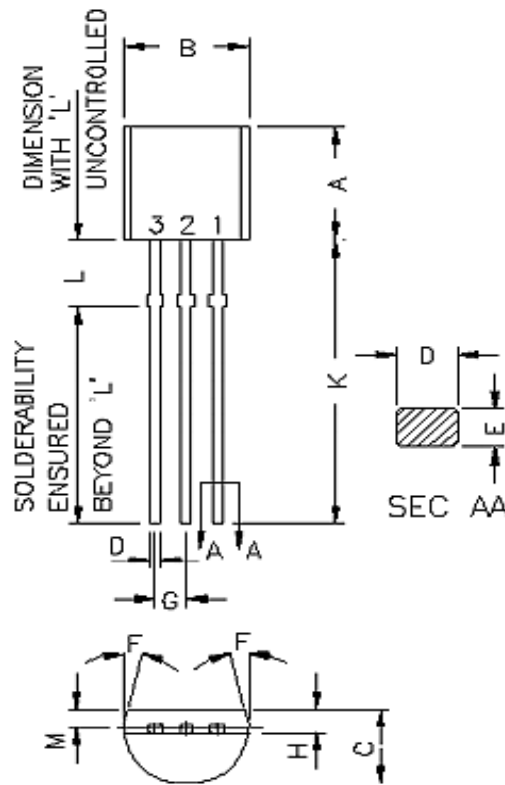


Fig 14: Active Region — Safe Operating Area



PACKAGE DETAILS

TO-92 Plastic Package



DIM	MIN	MAX
A	4.30	5.33
B	4.10	5.20
C	3.10	4.19
D	0.35	0.55
E	0.29	0.55
F	8 DEG	
G	1.14	1.40
H	1.00	1.80
K	11.50	--
L	1.982	2.082
M	1.03	1.53

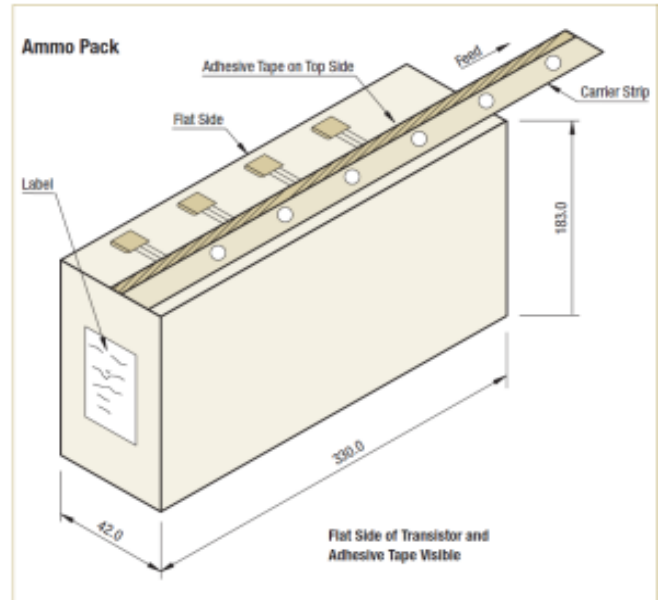
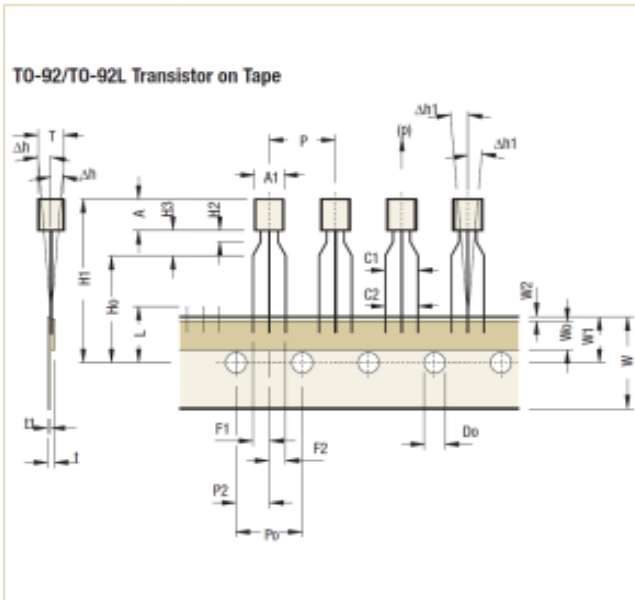
All dimensions are in mm

Package Specifications:

Package / Case Type	Packaging Type	Std. Packing		Inner Carton		Outer Carton		
		Qty	Qty	Size L x W x H (cm)	Gross Weight (Kg)	Qty	Size L x W x H (cm)	Gross Weight (Kg)
TO-92	Bulk	1,000	5K	19 x 19 x 8	1.1	80K	43 x 40 x 35	20.0
	T & A	2,000	2K	32 x 4.5 x 20	0.7	40K	43 x 40 x 35	15.2

PACKAGE DETAILS

TO-92 Tape and Ammo Package



Tape Specifications

Item description	Symbol	TO-92			
		Min	Nom	Max	Tol
Body width	A1	4.45		5.20	
Body height	A	4.32		5.33	
Body thickness	T	3.18		4.19	
Pitch of component ^{Cr}	P		12.7		±1.0
Feed hole pitch ^{§1}	Po		12.7		±0.3
Feed hole center to component centre ^{§2}	P2		6.35		±0.4
Comp. alignment, Side view ^{§3}	Dh		0	1.0	
Comp. alignment, Front view ^{§3}	Dh1		0	1.3	
Tape width ^{Cr}	W		18		±0.5
Hold down tape width ^{Cr}	Wo		6		±0.2
Hole position	W1		9		+0.7 -0.5
Hold-down tape position	W2	0.0		0.7	
Lead wire clinch height	Ho		16		±0.5
Component height	H1			24.0	
Length of snapped leads	L			11.0	
Feed hole diameter ^{Cr}	Do		4		±0.2
Total tape thickness ^{§4}	t			1.2	
Lead-to-lead distance ^{Cr}	F1, F2	2.4		2.7	
Stand off	H2	0.45		1.45	
Clinch height	H3			3.0	
Lead parallelism ^{Cr}	C1-C2			0.22	
Pull-out force	(p)	6N			

Taping Specification

- Maximum alignment deviation between leads not to be greater than 0.20 mm.
- Maximum non-cumulative variation between tape feed holes shall not exceed 1 mm in 20 pitches.
- Hold down tape not to exceed beyond the edge(s) carrier tape and there shall be no exposure of adhesive.
- No more than 3 consecutive missing components is permitted.
- A tape trailer, having at least three feed holes is required after the last component.
- Splices shall not interfere with the sprocket feed holes.

§1 Cumulative pitch error 1.0 mm/20 pitch.

§2 To be measured at bottom of clinch.

§3 At top of body.

§4 t1 – 0.3 – 0.6 mm

Cr Critical Dimension.



Recommended Product Storage Environment for Discrete Semiconductor Devices

This storage environment assumes that the Diodes and transistors are packed properly inside the original packing supplied by CDIL.

- Temperature 5 °C to 30 °C
- Humidity between 40 to 70 %RH
- Air should be clean.
- Avoid harmful gas or dust.
- Avoid outdoor exposure or storage in areas subject to rain or water spraying .
- Avoid storage in areas subject to corrosive gas or dust. Product shall not be stored in areas exposed to direct sunlight.
- Avoid rapid change of temperature.
- Avoid condensation.
- Mechanical stress such as vibration and impact shall be avoided.
- The product shall not be placed directly on the floor.
- The product shall be stored on a plane area. They should not be turned upside down. They should not be placed against the wall.

Shelf Life of CDIL Products

The shelf life of products is the period from product manufacture to shipment to customers. The product can be unconditionally shipped within this period. The period is defined as 2 years.

If products are stored longer than the shelf life of 2 years the products shall be subjected to quality check as per CDIL quality procedure.

The products are further warranted for another one year after the date of shipment subject to the above conditions in CDIL original packing.

Floor Life of CDIL Products and MSL Level

When the products are opened from the original packing, the floor life will start.

For this, the following JEDEC table may be referred:

JEDEC MSL Level		
Level	Time	Condition
1	Unlimited	≤30 °C / 85% RH
2	1 Year	≤30 °C / 60% RH
2a	4 Weeks	≤30 °C / 60% RH
3	168 Hours	≤30 °C / 60% RH
4	72 Hours	≤30 °C / 60% RH
5	48 Hours	≤30 °C / 60% RH
5a	24 Hours	≤30 °C / 60% RH
6	Time on Label(TOL)	≤30 °C / 60% RH



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Customer Notes

Component Disposal Instructions

1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.



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